

Thyristor High Voltage, Phase Control SCR, 50 A



PRIMARY CHARACTERISTICS						
I _{T(AV)}	50 A					
V _{DRM} /V _{RRM}	1200 V					
V _{TM} (typ.)	1.2 V					
I _{GT} (typ.)	45 mA					
T _J max.	150 °C					
Package	TO-247AD 3L					
Circuit configuration	Single SCR					

FEATURES

- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification



- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-50TPS12 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching, and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM} / V _{DRM}		1200	V			
On-state voltage	V _T	50 A, T _J = 125 °C	1.2	V			
Average rectified forward current	I _{T(AV)}		50				
Maximum continuous RMS on-state current	I _{RMS}		79	Α			
Non-repetitive peak surge current	I _{TSM}		630				
Maximum rate of rise	dv/dt		1000	V/µs			
Operating junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C			

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} / V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} / I _{DRM} AT 150 °C mA					
VS-50TPS12LHM3	1200	1300	70					



ABSOLUTE MAXIMUM RATING				TYP.		T
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T_C = 112 °C, 180° conduction half sine v	vave	-	50	
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}					Α
Peak, one-cycle non-repetitive surge current	I	10 ms sine pulse, rated V _{RRM} applied		-	530	
reak, one-cycle non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	Initial $T_J = T_J$	-	630	
I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	maximum	-	1405	A ² s
I-t for fusing	I-L	10 ms sine pulse, no voltage reapplied		-	1986	A-S
I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	d, T _J = 125 °C	-	19 850	A²√s
Low level value of threshold voltage	V _{T(TO)1}				0.89	V
High level value of threshold voltage	V _{T(TO)2}	T 405 00		-	0.97	v
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C			6.77	0
High level value of on-state slope resistance	r _{t2}			-	6.32	mΩ
On state voltage	V	50 A, T _J = 25 °C		1.2	1.32	V
On-state voltage	V_{T}	100 A, T _J = 25 °C		1.4	1.6	ľ
Rate of rise of turned-on current	di/dt	T _J = 25 °C		-	150	A/µs
Holding current	I _H	Anada ayanlır. 6.V vasistiya laad T	DE %C	-	300	
Latching current	ΙL	Anode supply = 6 V, resistive load, $T_J = 25 ^{\circ}\text{C}$			350	
Davis and direct lealings are surrect	. //	T _J = 25 °C		-	0.05	mA
Reverse and direct leakage current	I _{RRM} /I _{DRM}	T _J = 150 °C			70	
Rate of rise of off-state voltage	dv/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , l	R_q -k = 100 Ω	-	1000	V/µs

TRIGGERING								
PARAMETER	SYMBOL		TEST CONDITIONS	TYP.	MAX.	UNITS		
Peak gate power	P _{GM}	10 ma aina nula	se, no voltage reapplied	-	10	W		
Average gate power	P _{G(AV)}	TO THS SITIE PUIS	se, no voltage reapplied	-	2.5	l vv		
Peak gate current	I _{GM}			-	2.5	Α		
Peak negative gate voltage	-V _{GM}			-	10			
		T _J = -40 °C	Anode supply = 6 V resistive load	-	1.6	V		
Required DC gate voltage to trigger	V_{GT}	T _J = 25 °C		=	1.5]		
		T _J = 150 °C		=	1			
		T _J = -40 °C		-	160			
Required DC gate to trigger	I_{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	45	100	mA		
		T _J = 150 °C		-	60			
DC gate voltage not to trigger	V_{GD}	T _J = 150 °C, V _{DRM} = rated value			0.2	V		
DC gate current not to trigger	I_{GD}	$I_{\rm J} = 150^{\circ} \rm C, V_{\rm D}$	_{DRM} = rated value	-	3	mA		

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Turn-on time	t _{gt}	$I_T = 50 \text{ A}, V_D = 50 \% V_{DRM}, I_{gt} = 300 \text{ mA}, T_J = 25 °C$	1.5	ı	
Turn-off time	t _q	I_T = 50 A, V_D = 80 % V_{DRM} , dV/dt = 20 $V/\mu s$, t_p = 200 μs I_{gt} = 100 mA, dI/dt = 10 $A/\mu s$, V_R = 100 V , T_J = 150 °C	92	-	μs



THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS		
Maximum junction and storage te	emperature range	T _J , T _{Stg}		-40	150	°C		
Maximum thermal resistance, junction to case		R_{thJC}		-	0.35			
Maximum thermal resistance, jun	ction to ambient	R_{thJA}		-	40	°C/W		
Typical thermal resistance, case t	Typical thermal resistance, case to heatsink		Mounting surface, smooth, and greased	0.2	-			
Mounting torque	minimum			6 (5)		kgf · cm		
Woulding torque	maximum			12 (10)		(lbf · in)		
Marking device			Case style Super TO-247AD 3L	;	50TPS12L	Н		

ΔR_{thJ-HS} CONDUCTION PER JUNCTION											
SINE HALF-WAVE CONDUCTION				RECTANGULAR WAVE CONDUCTION				UNITS			
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VS-50TPS12LHM3	0.143	0.166	0.208	0.299	0.490	0.099	0.168	0.223	0.311	0.494	°C/W

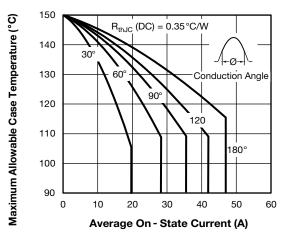


Fig. 1 - Current Rating Characteristics

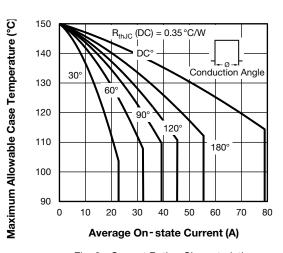


Fig. 2 - Current Rating Characteristics

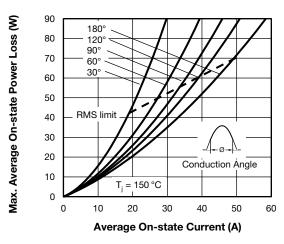


Fig. 3 - On-State Power Loss Characteristics

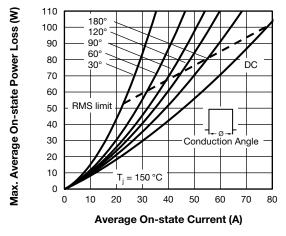
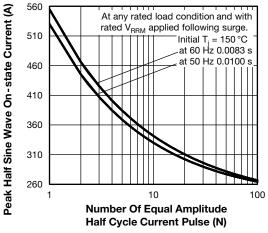


Fig. 4 - On-State Power Loss Characteristics





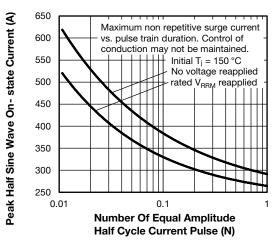


Fig. 6 - Maximum Non-Repetitive Surge Current

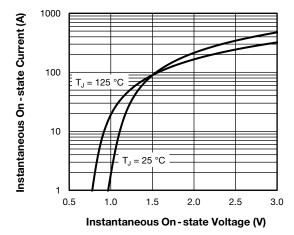
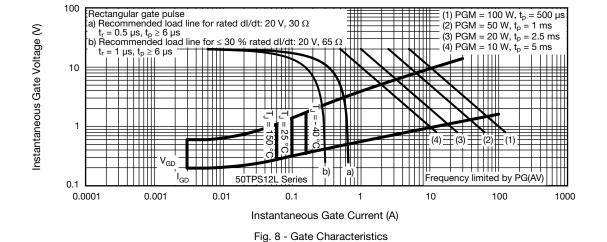


Fig. 7 - On-State Voltage Drop Characteristics



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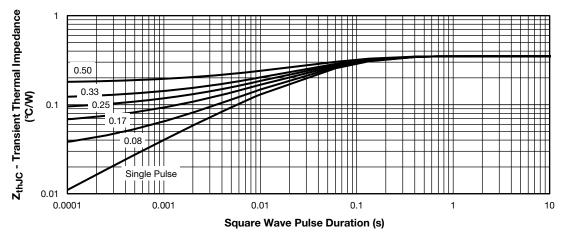
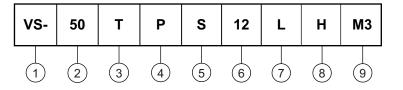


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Dev	ice	code	3



- 1 Vishay Semiconductors product
- 2 Current code (50 = 50 A)
- 3 Circuit configuration:
 - T = thyristor
- 4 P = TO-247AD package
- 5 Type of silicon:

S = standard recovery rectifier

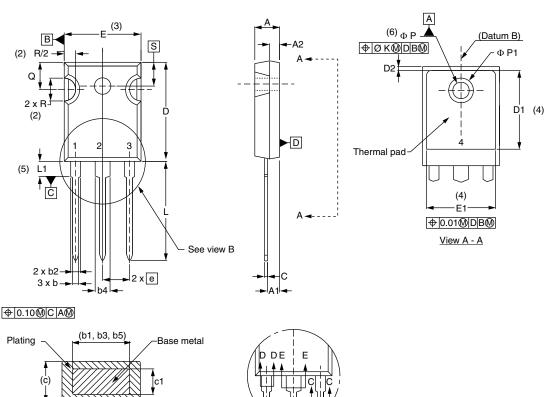
- 6 Voltage code (12 = 1200 V)
- 7 Package L = long lead
- 8 H = AEC-Q101 qualified
- 9 M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-50TPS12LHM3	25	contact factory	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626				
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007				

TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIM	MILLIMETERS		HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
О	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	ı	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
•	•			•	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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